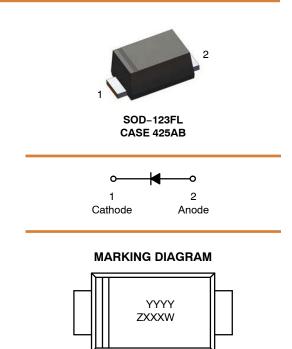
onsemi

Super Fast Surface Mount Rectifiers US1AFA-US1MFA

Features

- Glass Passivated Chip Junction
- Low Power Loss, High Efficiency
- Fast Switching Reverse Recovery Time: 50~75 ns Maximum
- High Surge Capacity
- UL Flammability 94V–0 Classification
- MSL 1 per J-STD-020
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant



- YYYY = Binary Calendar Year Code Scheme
 - = Assembly Plant Code

Ζ

W

- XXX = Specific Device Code
 - = Single Digit Week Code

ORDERING INFORMATION

Part Number	Device Code Marking	Package	Shipping [†]			
US1AFA, NRVUS1AFA*	HAL	SOD-123FL	3,000 / Tape & Reel			
US1BFA, NRVUS1BFA*	HBL	(Pb-Free / Halogen Free)				
US1DFA, NRVUS1DFA*	HDL					
US1FFA, NRVUS1FFA*	HFL					
US1GFA, NRVUS1GFA*	HGL					
US1JFA, NRVUS1JFA*	HJL					
US1KFA, NRVUS1KFA*	HKL					
US1MFA, NRVUS1MFA*	HML	7				

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

US1AFA-US1MFA

ABSOLUTE MAXIMUM RATINGS (Values are at $T_A = 25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	US1 AFA	US1 BFA	US1 DFA	US1 FFA	US1 GFA	US1 JFA	US1 KFA	US1 MFA	Unit
V _{RRM}	Repetitive Peak Reverse Voltage		100	200	300	400	600	800	1000	V
V _{RMS}	RMS Reverse Voltage		70	140	210	280	420	560	700	V
V _R	DC Blocking Voltage	50	100	200	300	400	600	800	1000	V
I _{F(AV)}	Average Forward Rectified Current	1			А					
I _{FSM}	Peak Forward Surge Current: 8.3 ms Single Half Sine-Wave Superimposed on Rated Load	30		A						
TJ	Operating Junction Temperature Range	-55 to +150		°C						
T _{STG}	Storage Temperature Range	-55 to +150				°C				

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS (Values are at $T_A = 25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	Value	Unit	
Ψ_{JL}	Typical Thermal Resistance, Junction to Lead	21	°C/W	
$R_{\theta JA}$	Typical Thermal Resistance, Junction to Ambient	153	°C/W	

NOTE: Device mounted at minimum pad.

ELECTRICAL CHARACTERISTICS (Values are at $T_A = 25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	Conditions	US1 AFA	US1 BFA	US1 DFA	US1 FFA	US1 GFA	US1 JFA	US1 KFA	US1 MFA	Unit
V _F	Maximum Instantaneous Forward Voltage (Note 1)	I _F = 1 A	0.95 1.30 1.70			V					
I _R	Maximum Reverse Current at Rated V _R	T _J = 25°C	5							μA	
		T _J = 125°C	150								
CJ	Typical Junction Capacitance	V _R = 4.0 V, f = 1.0 MHz	20				15		pF		
T _{rr}	Maximum Reverse Recovery Time	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A	50		75		ns				

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse test with PW = 300 μ s, 1% duty cycle.

US1AFA-US1MFA

TYPICAL PERFORMANCE CHARACTERISTICS

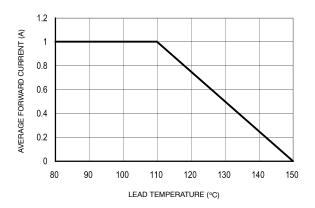


Figure 1. Maximum Forward Current Derating Voltage

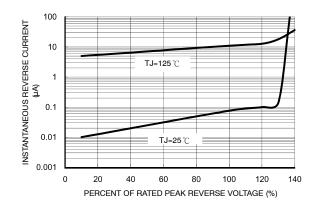


Figure 2. Typical Reverse Characteristics

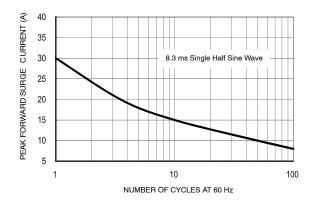
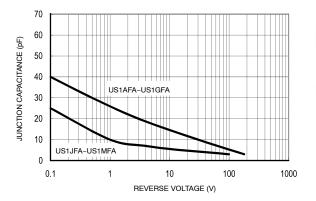


Figure 3. Maximum Non-Repetitive Forward Surge Current





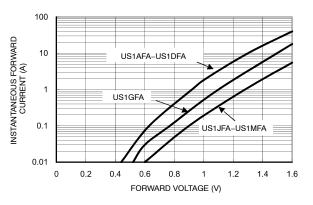


Figure 4. Typical Instantaneous Forward Characteristics

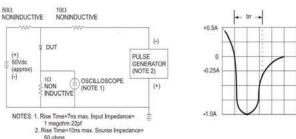
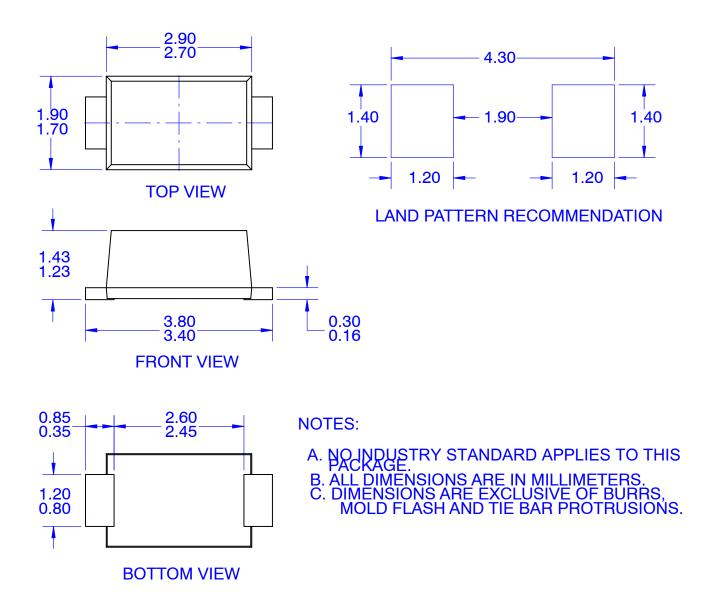


Figure 6. Reverse Recovery Time Characteristic and Test Circuit Diagram



SOD-123FL CASE 425AB ISSUE O

DATE 31 AUG 2016



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